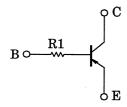
TOSHIBA Transistor Silicon PNP Epitaxial Type (PCT Process)

RN2310,RN2311

Switching, Inverter Circuit, Interface Circuit And Driver Circuit Applications

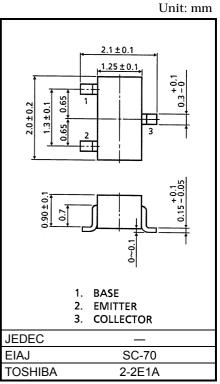
- With built-in bias resistors
- Simplify circuit design
- Reduce a quantity of parts and manufacturing process
- Complementary to RN1310, RN1311

Equivalent Circuit



Maximum Ratings (Ta = 25°C)

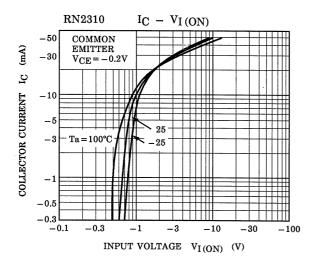
Characterisstic	Symbol	Rating	Unit
Collector-base voltage	V _{CBO}	-50	V
Collector-emitter voltage	V _{CEO}	-50	V
Emitter-base voltage	V _{EBO}	-5	V
Collector current	Ic	-100	mA
Collector power dissipation	PC	100	mW
Junction temperature	Tj	150	°C
Storage temperature range	T _{stg}	-55~150	°C

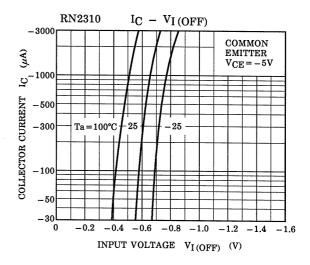


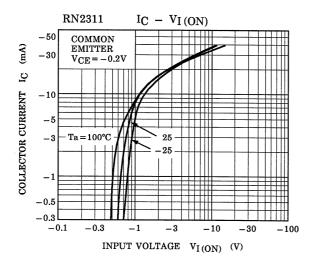
Weight: 0.006g

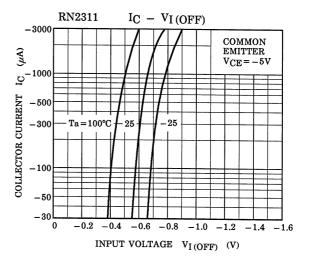
Electrical Characteristics (Ta = 25°C)

Characteristic		Symbol	Test Circuit	Test Condition	Min	Тур.	Max	Unit
Collector cut-off current		I _{CBO}	_	$V_{CB} = -50V, I_{E} = 0$	_	_	-100	nA
Emitter cut-off current		I _{EBO}	_	$V_{EB} = -5V, I_C = 0$	_	_	-100	nA
DC current gain		h _{FE}	_	V _{CE} = −5V, I _C = −1mA	120	_	400	_
Collector-emitter saturation voltage		V _{CE} (sat)	_	$I_C = -5mA$, $I_B = -0.25mA$	_	-0.1	-0.3	V
Translation Frequency		f _T	_	V _{CE} = −10V, I _C = −5mA	_	200	_	MHz
Collector output capacitance		C _{ob}	_	V _{CB} = −10V, I _E = 0, f = 1MHz	_	3	6	pF
Input resistor	RN2310	R1	_	_	3.29	4.7	6.11	kΩ
	RN2311				7	10	13	

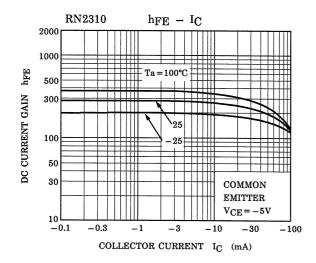


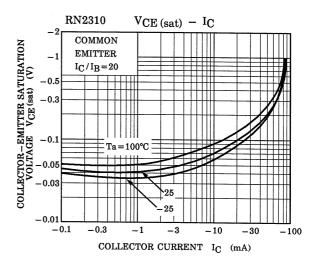


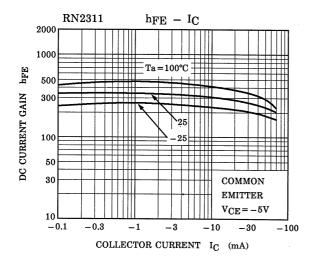


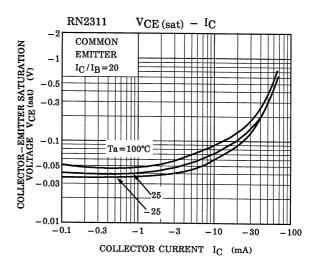


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Type Name	Marking	
RN2310	Type Name Y K	
RN2311	Type Name Y M	

2001-06-07

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RESTRICTIONS ON PRODUCT USE

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